



Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from,Europe,America and south Asia,supplying obsolete and hard-to-find components to meet their specific needs.

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We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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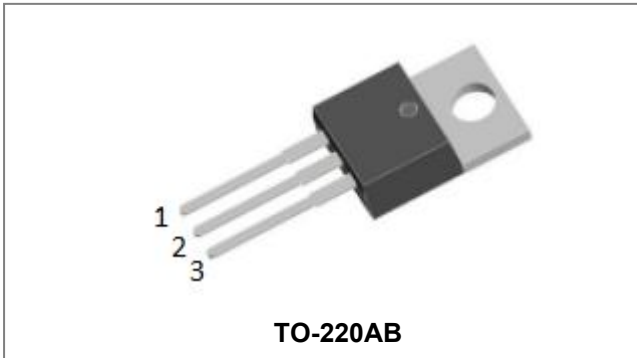
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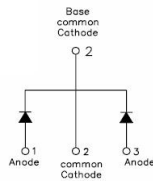
MBR40200CT SCHOTTKY RECTIFIER



Features

- 150°C T_J operation
- Center tap configuration
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced
- mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- This is a Pb – Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Circuit Diagram



Applications

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

Maximum Ratings:

| Characteristics | Symbol | Condition | Max. | Units |
|--|--|--|-------------------------------|-------|
| Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage | V _{RRM} V _{RWM} V _R | - | 200 | V |
| Average Rectified Forward Current | I _{F(AV)} | 50% duty cycle @T _c =110°C, rectangular wave form | 20(Per Leg) 40(Per Device) | A |
| Peak Repetitive Forward Current(Per Leg) | I _{FRM} | Rated V _R square wave, 20KHz T _C =133°C | 20 | A |
| Peak One Cycle Non-Repetitive Surge Current(Per Leg) | I _{FSM} | 8.3ms, Half Sine pulse, T _C = 25 °C | 396 | A |

Electrical Characteristics:

| Characteristics | Symbol | Condition | Typ. | Max. | Units |
|--------------------------------|-----------------|---|--------|--------|-------|
| Forward Voltage Drop(Per Leg)* | V _{F1} | @ 20A, Pulse, T _J = 25 °C | 0.85 | 0.90 | V |
| | V _{F2} | @ 20A, Pulse, T _J = 25 °C | 0.72 | 0.80 | V |
| Reverse Current(Per Leg)* | I _{R1} | @V _R = rated V _R , T _J = 25 °C | 0.0001 | 1.0 | mA |
| | I _{R2} | @V _R = rated V _R , T _J = 125 °C | 0.1 | 11 | mA |
| Junction Capacitance(Per Leg) | C _T | @V _R = 5V, T _C = 25 °C f _{SIG} = 1MHz | 300 | 450 | pF |
| Series Inductance(Per Leg) | L _S | Measured lead to lead 5 mm from package body | 8.0 | - | nH |
| Voltage Rate of Change | dv/dt | - | - | 10,000 | V/μs |

* Pulse width < 300 μs, duty cycle < 2%

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Thermal-Mechanical Specifications:

| Characteristics | Symbol | Condition | Specification | Units |
|--|-----------------------|--------------------------------------|---------------|----------------------|
| Junction Temperature | T_J | - | -55 to +150 | $^{\circ}\text{C}$ |
| Storage Temperature | T_{stg} | - | -55 to +150 | $^{\circ}\text{C}$ |
| Typical Thermal Resistance Junction to Case | $R_{\theta\text{JC}}$ | DC operation | 2.0 | $^{\circ}\text{C/W}$ |
| Typical Thermal Resistance Junction to Ambient | $R_{\theta\text{JA}}$ | DC operation | 50 | $^{\circ}\text{C/W}$ |
| Typical Thermal Resistance, Case to Heat Sink | $R_{\theta\text{JS}}$ | Mounting surface, smooth and greased | 0.50 | $^{\circ}\text{C/W}$ |
| Approximate Weight | wt | - | 2 | g |

Ratings and Characteristics Curves

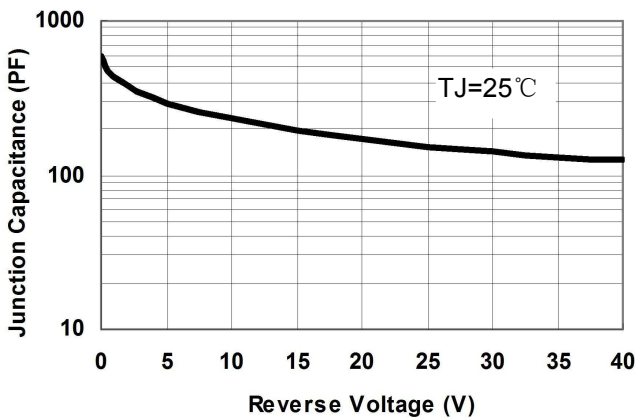


Fig.1-Typical Junction Capacitance

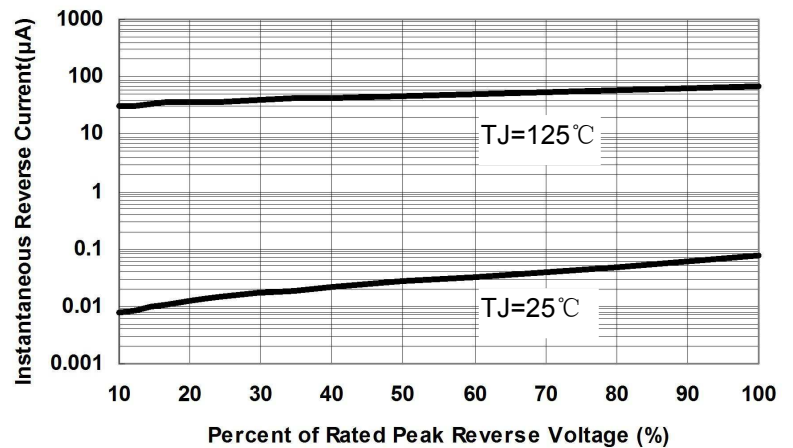


Fig.2-Typical Reverse Characteristics

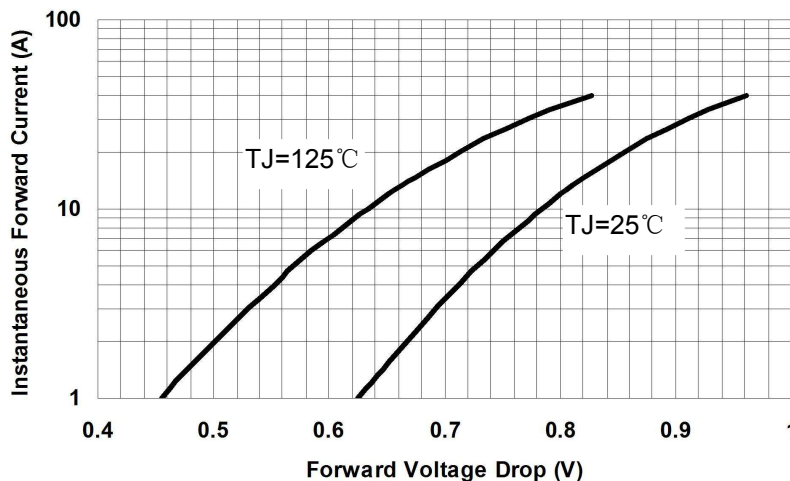
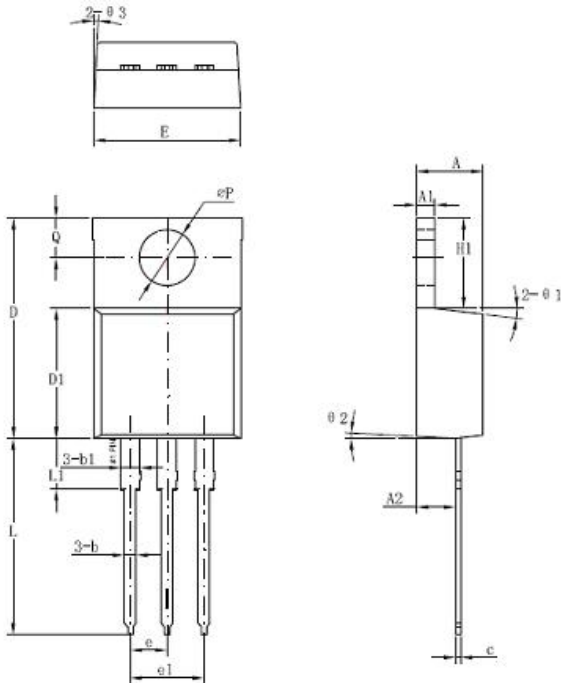


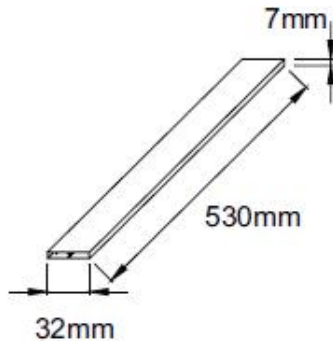
Fig.3-Typical Instantaneous Forward Voltage Characteristics

Mechanical Dimensions TO-220AB

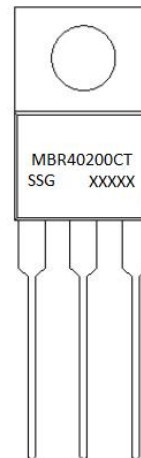


| Symbol | Dimensions in millimeters | | |
|--------|---------------------------|---------|-------|
| | Min | Typical | Max |
| A | 4.42 | 4.57 | 4.72 |
| A1 | 1.17 | 1.27 | 1.37 |
| A2 | 2.52 | 2.69 | 2.89 |
| b | 0.71 | 0.81 | 0.96 |
| b1 | 1.17 | 1.27 | 1.37 |
| c | 0.31 | 0.38 | 0.61 |
| D | 14.94 | 15.24 | 15.54 |
| D1 | 8.85 | 9.00 | 9.15 |
| E | 10.01 | 10.16 | 10.31 |
| e | | 2.54 | |
| e1 | 4.98 | 5.06 | 5.18 |
| H1 | 6.04 | 6.24 | 6.44 |
| L | 12.7 | 13.56 | 13.80 |
| L1 | 3.56 | 3.5 | 3.96 |
| ΦP | 3.74 | 3.84 | 4.04 |
| Q | 2.54 | 2.74 | 2.94 |
| θ1 | | 7° | |
| θ2 | | 3° | |
| θ3 | | 4° | |

Tube Specification



Marking Diagram



Where XXXXX is YYWWL

MBR = Device Type
40 = Forward Current (40A)
200 = Reverse Voltage(200V)
CT = Configuration
SSG = SSG
YY = Year
WW = Week
L = Lot Number

Cautions: Molding resin
Epoxy resin UL:94V-0

Ordering Information

| Device | Package | Shipping |
|------------|--------------------|--------------|
| MBR40200CT | TO-220AB (Pb-Free) | 50 pcs/ tube |

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

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